



Page i

**INTEGRATED CIRCUITS, SILICON MONOLITHIC,
BIPOLEAR, ADVANCED LOW POWER SCHOTTKY,
OCTAL BUS TRANSCEIVERS WITH
3-STATE OUTPUTS,
BASED ON TYPES 54ALS245A AND 54ALS645A
ESCC Detail Specification No. 9405/005**

**ISSUE 1
October 2002**



Document Custodian: European Space Agency - see <https://escies.org>

	ESCC Detail Specification		PAGE ii ISSUE 1
---	---------------------------	--	--------------------------

LEGAL DISCLAIMER AND COPYRIGHT

European Space Agency, Copyright © 2002. All rights reserved.

The European Space Agency disclaims any liability or responsibility, to any person or entity, with respect to any loss or damage caused, or alleged to be caused, directly or indirectly by the use and application of this ESCC publication.

This publication, without the prior permission of the European Space Agency and provided that it is not used for a commercial purpose, may be:

- copied in whole in any medium without alteration or modification.
- copied in part, in any medium, provided that the ESCC document identification, comprising the ESCC symbol, document number and document issue, is removed.



european space agency
agence spatiale européenne

Pages 1 to 30



INTEGRATED CIRCUITS, SILICON MONOLITHIC,
BIPOLAR, ADVANCED LOW POWER SCHOTTKY,
OCTAL BUS TRANSCEIVERS WITH
3-STATE OUTPUTS,
BASED ON TYPES 54ALS245A AND 54ALS645A

ESA/SCC Detail Specification No. 9405/005



space components
coordination group

Issue/Rev.	Date	Approved by	
		SCCG Chairman	ESA Director General or his Deputy
Issue 3	February 1992	<i>Pommerehne</i>	<i>J. Loh</i>
Revision 'A'	June 1994	<i>Pommerehne</i>	<i>Jos Loh</i>

 	<p>ESA/SCC Detail Specification No. 9405/005</p>	<p>Rev. 'A'</p>	<p>PAGE 2 ISSUE 3</p>
---	--	-----------------	---------------------------

DOCUMENTATION CHANGE NOTICE

Rev. Letter	Rev. Date	Reference	CHANGE Item	Approved DCR No.
		This Issue supersedes Issue 2 and incorporates all modifications defined in the following DCR's:- Cover Page DCN Table 1(a) Figures 2 Figure 2(a) Figure 2(c) Notes to Figures Figure 3(a) Figure 3(b) Para. 4.2.2 Para. 4.2.4 Para. 4.2.5 Para. 4.3.2 Para. 4.4.2 Para. 4.5.2 Para. 4.5.3 Para. 4.6.3 Para. 4.7.1 Figures 4(a),(c) Para. 4.8	: Lead Material and/or Finish amended : Variant 02 added and Figure references amended : Imperial dimensions and references deleted : New Figure 2(a) added and previous Figures 2(a) and 2(b) renumbered "2(b) "and "2(c)" : In drawing, Note 6 corrected to "10" : Title amended : Note 1, amended to read "...Figure 2(b)" : Note 2, text amended : Note 9, text amended : DIL subtitle added : In Table, under Output, last line amended to "Z" : Note added : Deviation deleted, "None." added : Deviation deleted, "None." added : Deviation deleted, "None." added : Flat Package weight added : Paragraph amended : Paragraph amended : "Type Variant, as applicable" amended to refer to Table 1(a) : Reference to functional test sequence deleted : Expanded to identify the stated temperature as T _{amb} : Figures corrected : Title expanded	None None 22881 22920 22881 22920 23456 22881 22881 22920 22920 22920 23456 23456 21048 22919 22919 22920 22881/ 22920 22881/ 22920 23455 23455 23455 23456 23455
'A'	June '94	P1. Cover Page P2. DCN P14. Para. 4.3.2	: Weights amended	None None 221047





 	<p>ESA/SCC Detail Specification No. 9405/005</p>	<p>PAGE 3 ISSUE 3</p>
---	--	---------------------------

TABLE OF CONTENTS

	<u>Page</u>
1. <u>GENERAL</u>	5
1.1 Scope	5
1.2 Component Type Variants	5
1.3 Maximum Ratings	5
1.4 Parameter Derating Information	5
1.5 Physical Dimensions	5
1.6 Pin Assignment	5
1.7 Truth Table	5
1.8 Circuit Schematic	5
1.9 Functional Diagram	5
2. <u>APPLICABLE DOCUMENTS</u>	13
3. <u>TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS</u>	13
4. <u>REQUIREMENTS</u>	13
4.1 General	13
4.2 Deviations from Generic Specification	13
4.2.1 Deviations from Special In-process Controls	13
4.2.2 Deviations from Final Production Tests	13
4.2.3 Deviations from Burn-in Tests	13
4.2.4 Deviations from Qualification Tests	13
4.2.5 Deviations from Lot Acceptance Tests	14
4.3 Mechanical Requirements	14
4.3.1 Dimension Check	14
4.3.2 Weight	14
4.4 Materials and Finishes	14
4.4.1 Case	14
4.4.2 Lead Material and Finish	14
4.5 Marking	14
4.5.1 General	14
4.5.2 Lead Identification	14
4.5.3 The SCC Component Number	15
4.5.4 Traceability Information	15
4.6 Electrical Measurements	15
4.6.1 Electrical Measurements at Room Temperature	15
4.6.2 Electrical Measurements at High and Low Temperatures	15
4.6.3 Circuits for Electrical Measurements	15
4.7 Burn-in Tests	15
4.7.1 Parameter Drift Values	15
4.7.2 Conditions for Power Burn-in	15
4.7.3 Electrical Circuits for Power Burn-in	15
4.8 Environmental and Endurance Tests	28
4.8.1 Electrical Measurements on Completion of Environmental Tests	28
4.8.2 Electrical Measurements at Intermediate Points during Endurance Tests	28
4.8.3 Electrical Measurements on Completion of Endurance Tests	28
4.8.4 Conditions for Operating Life Tests	28
4.8.5 Electrical Circuits for Operating Life Tests	28
4.8.6 Conditions for High Temperature Storage Test	28

 	<p>ESA/SCC Detail Specification No. 9405/005</p>		<p>PAGE 4 ISSUE 3</p>
---	--	--	---------------------------

Page

TABLES

1(a)	Type Variants	6
1(b)	Maximum Ratings	6
2	Electrical Measurements at Room Temperature, d.c. Parameters	16
	Electrical Measurements at Room Temperature, a.c. Parameters	18
3	Electrical Measurements at High and Low Temperatures	20
4	Parameter Drift Values	26
5	Conditions for Power Burn-in and Operating Life Test	26
6	Electrical Measurements on Completion of Environmental Tests and at Intermediate Points and on Completion of Endurance Tests	29

FIGURES

1	Not applicable	
2	Physical Dimensions	7
3(a)	Pin Assignment	11
3(b)	Truth Table	11
3(c)	Circuit Schematic	12
3(d)	Functional Diagram	12
4	Circuits for Electrical Measurements	22
5	Electrical Circuit for Power Burn-in and Operating Life Test	27

APPENDICES (Applicable to specific Manufacturers only)

'A'	Agreed Deviations for Texas Instruments (F)	30
-----	---	----

**SCC**ESA/SCC Detail Specification
No. 9405/005

PAGE 5

ISSUE 3

1. GENERAL**1.1 SCOPE**

This specification details the ratings, physical and electrical characteristics, test and inspection data for a silicon monolithic, bipolar, advanced low power Schottky, Octal Bus Transceiver with 3-State Outputs, based on Types 54ALS245A and 54ALS645A. It shall be read in conjunction with ESA/SCC Generic Specification No. 9000, the requirements of which are supplemented herein.

1.2 COMPONENT TYPE VARIANTS

Variants of the basic type integrated circuits specified herein, which are also covered by this specification, are given in Table 1(a).

1.3 MAXIMUM RATINGS

The maximum ratings, which shall not be exceeded at any time during use or storage, applicable to the integrated circuits specified herein, are as scheduled in Table 1(b).

1.4 PARAMETER DERATING INFORMATION (FIGURE 1)

Not applicable.

1.5 PHYSICAL DIMENSIONS

The physical dimensions of the integrated circuits specified herein are shown in Figure 2.

1.6 PIN ASSIGNMENT

As per Figure 3(a).

1.7 TRUTH TABLE

As per Figure 3(b).

1.8 CIRCUIT SCHEMATIC

As per Figure 3(c).

1.9 FUNCTIONAL DIAGRAM

As per Figure 3(d).

**TABLE 1(a) - TYPE VARIANTS**

VARIANT	BASED ON TYPE	CASE	FIGURE	LEAD MATERIAL AND/OR FINISH
02	245A or 645A	FLAT	2(a)	G4
03	245A or 645A	CCP	2(b)	7
04	245A or 645A	CCP	2(b)	4
05	245A or 645A	DIL	2(c)	D7
06	245A or 645A	DIL	2(c)	G4

TABLE 1(b) - MAXIMUM RATINGS

NO.	CHARACTERISTICS	SYMBOL	MAXIMUM RATINGS	UNIT	REMARKS
1	Supply Voltage	V_{CC}	−0.5 to 7.0	V	-
2	Input Voltage	V_{IN}	−0.5 to 7.0	V	Note 1
3	Input Voltage I/O Ports	V_{IN}	5.5	V	-
4	Device Dissipation	P_D	346.5	mWdc	Note 2
5	Operating Temperature Range	T_{op}	−55 to +125	°C	-
6	Storage Temperature Range	T_{stg}	−65 to +150	°C	-
7	Soldering Temperature For DIP For CCP	T_{sol}	+265 +245	°C	Note 3 Note 4

NOTES

1. Input Current limited to −18mA.
2. Must withstand added P_D due to short circuit conditions (i.e. I_{OS}) at 1 output for 5 seconds.
3. Duration 10 seconds maximum at a distance of not less than 1.5mm from the package and the same lead shall not be resoldered until 3 minutes have elapsed.
4. Duration 5 seconds maximum and the same terminal shall not be resoldered until 3 minutes have elapsed.



SCC

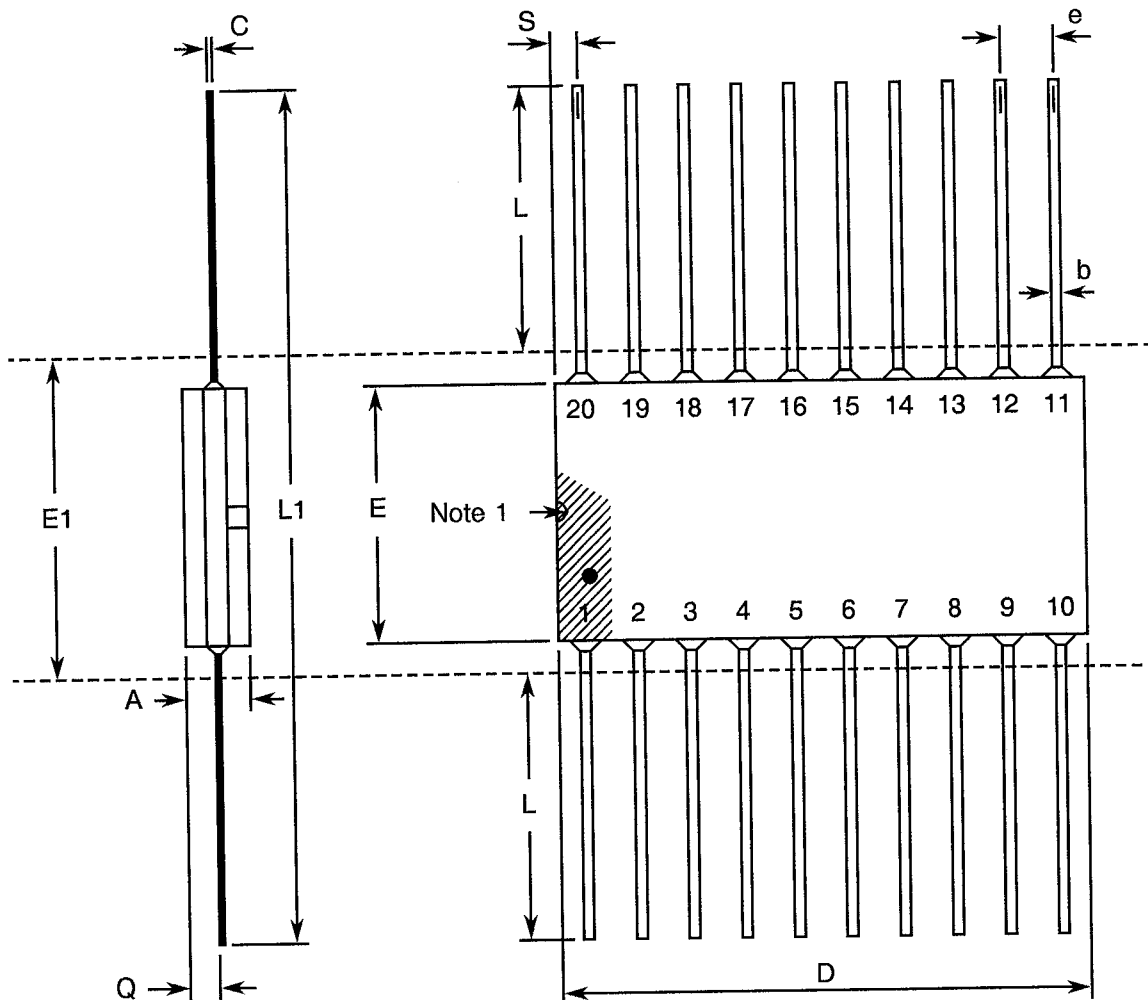
ESA/SCC Detail Specification
No. 9405/005

PAGE 7

ISSUE 3

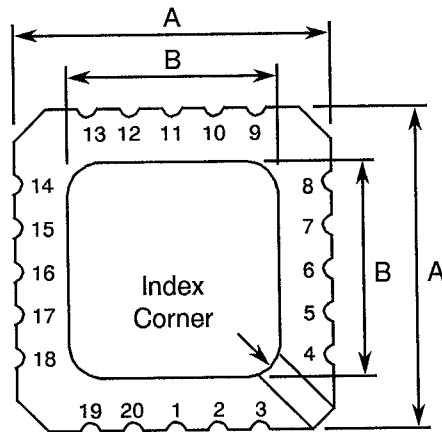
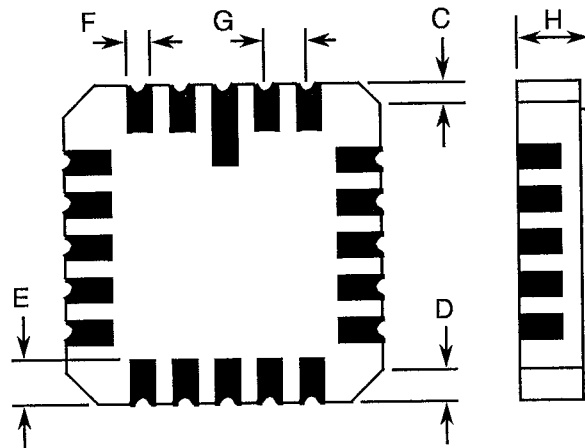
FIGURE 2 - PHYSICAL DIMENSIONS

FIGURE 2(a) - FLAT PACKAGE



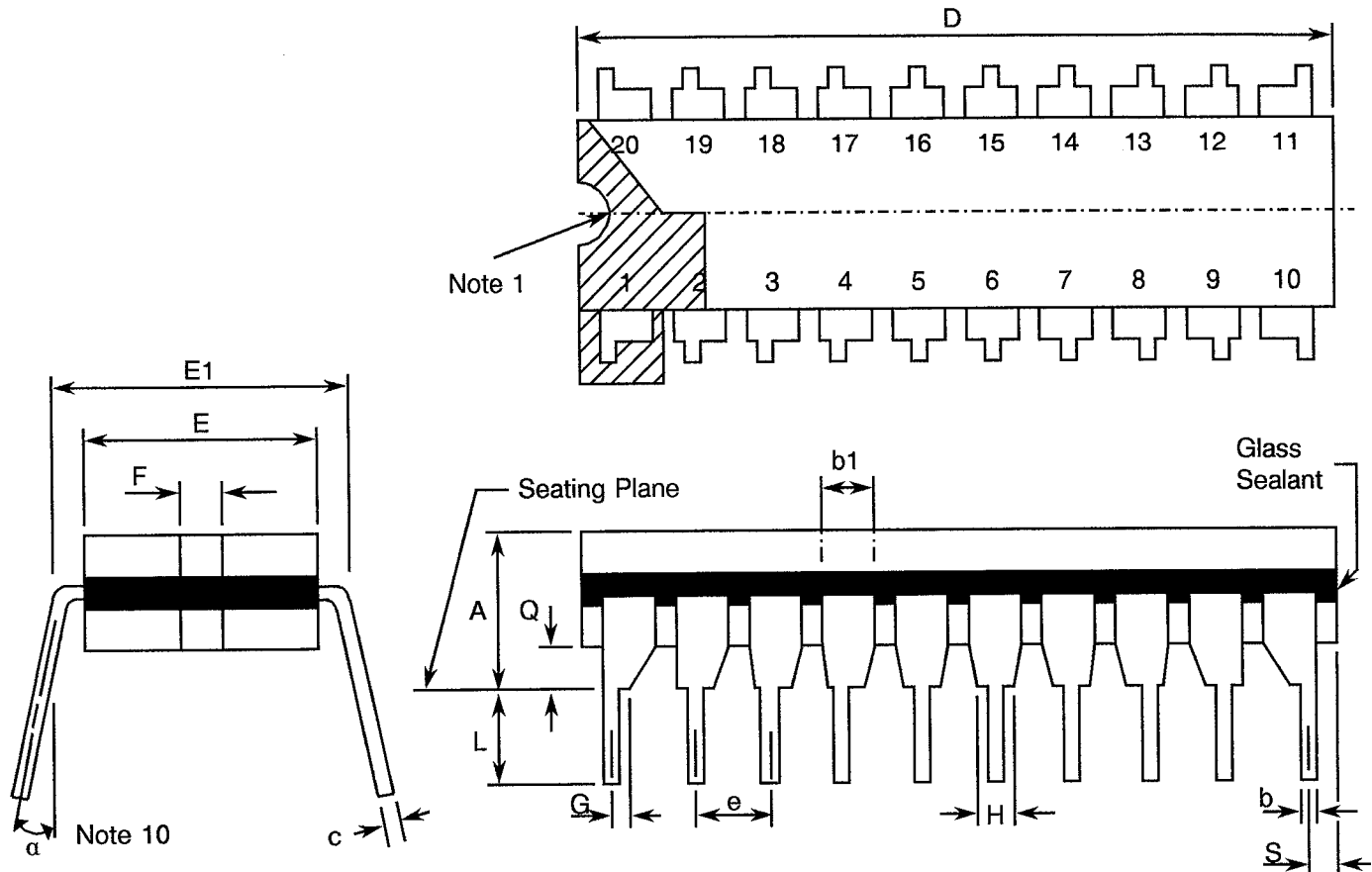
SYMBOL	MILLIMETRES		NOTES
	MIN	MAX	
A	1.14	2.34	
b	0.38	0.56	8
C	0.08	0.23	8
D	-	12.95	4
E	6.60	7.65	
E1	8.15 TYPICAL		4
e	1.27 TYPICAL		5, 9
L	6.35	9.40	8
L1	18.90	25.90	
Q	0.25	1.02	2
S	0.13	1.14	7

NOTES: See Page 10.

**FIGURE 2 - PHYSICAL DIMENSIONS****FIGURE 2(b) - SQUARE CHIP CARRIER PACKAGE (3 LAYER BASE)**20 Terminal

SYMBOL	MILLIMETRES		NOTES
	MIN	MAX	
A	8.687	9.093	
B	7.798	9.093	
C	0.250	0.510	11
D	0.889	1.143	12
E	1.140	1.400	8
F	0.559	0.712	8
G	1.27 TYPICAL		5, 9
H	1.630	2.540	

NOTES: See Page 10.

**FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)****FIGURE 2(c) - DUAL-IN-LINE PACKAGE**

SYMBOL	MILLIMETRES		NOTES
	MIN	MAX	
A	-	5.08	
b	0.38	0.58	8
b1	0.76	1.78	8
c	0.203	0.356	8
D	23.62	24.76	
E	6.22	7.62	
E1	7.37	7.87	4
e	2.54 TYPICAL		6, 9
F	1.27 TYPICAL		
G	0.305	-	13
H	0.76	-	14
L	3.30	5.08	
Q	0.51	2.03	3
S	0.38	1.27	7
α	0°	15°	10

NOTES: See Page 10.


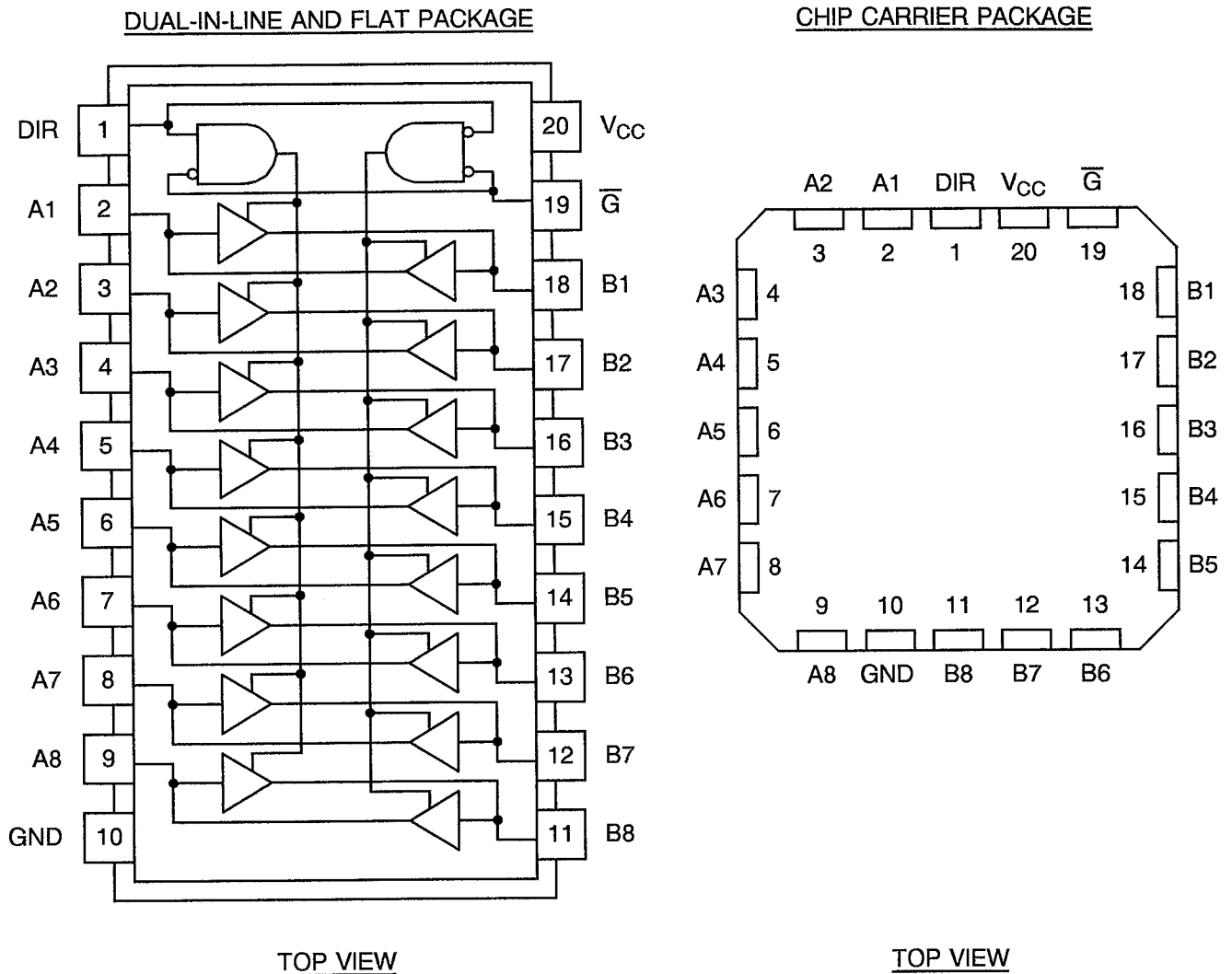
	<p>ESA/SCC Detail Specification No. 9405/005</p>	<p>PAGE 10 ISSUE 3</p>
---	--	----------------------------

FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)

NOTES TO FIGURES 2(a) TO 2(c) INCLUSIVE

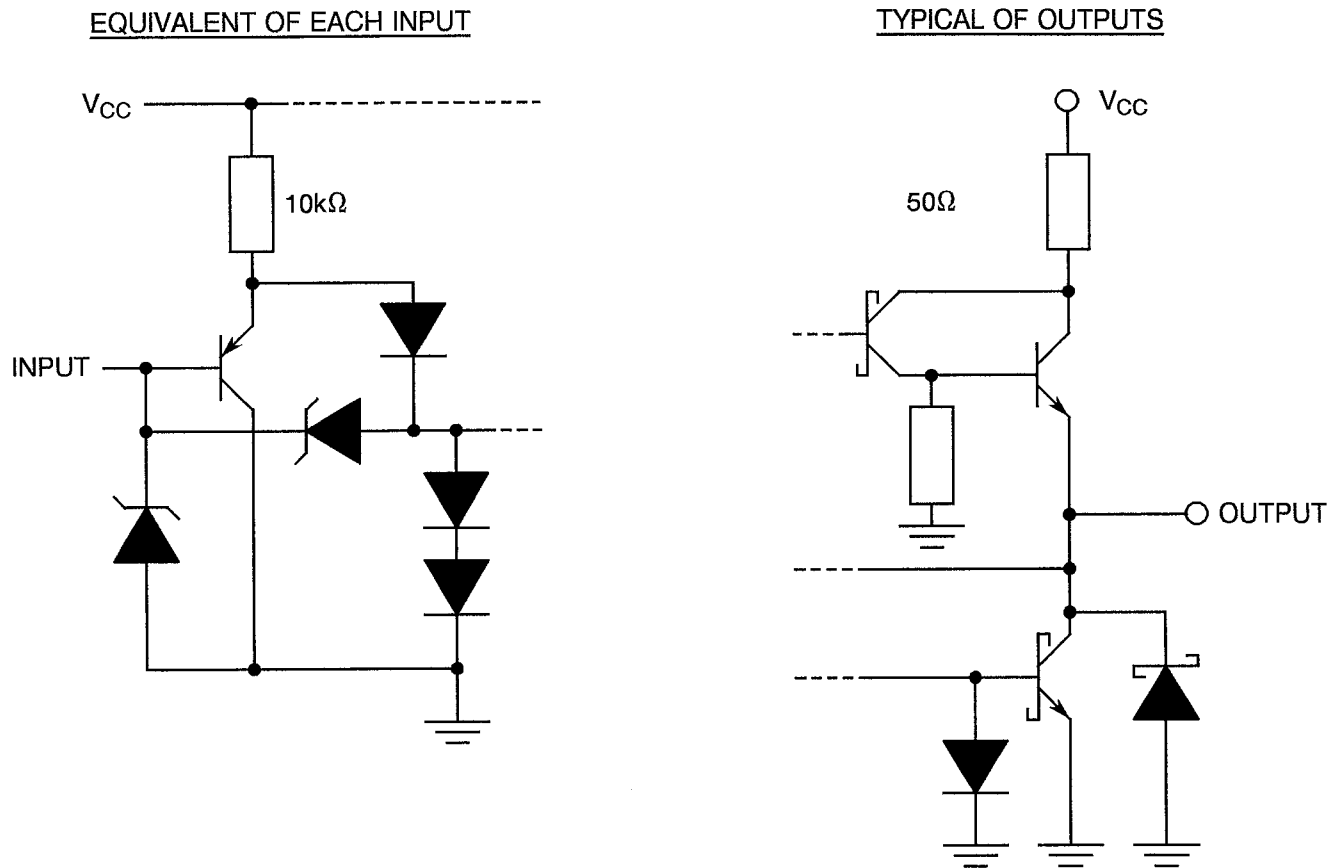
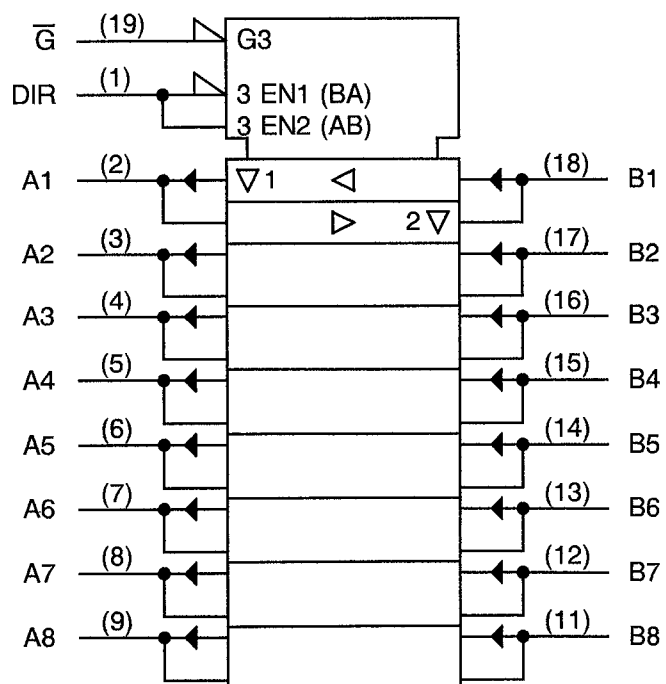
1. Index area; a notch or dot shall be located adjacent to Pin 1 and shall be within the shaded area shown. For chip carrier packages the index shall be as defined in Figure 2(b).
2. Dimension Q shall be measured at the point of exit of the lead from the body.
3. Dimension Q shall be measured from the seating plane to the base plane.
4. This dimension allows for off-centre lids, meniscus and glass overrun.
5. The true position pin or terminal spacing is 1.27mm between centrelines. Each pin or terminal centreline shall be located within $\pm 0.13\text{mm}$ of its true longitudinal position relative to Pins 1 and the highest pin number.
6. The true position pin spacing is 2.54mm between centrelines. Each pin centreline shall be located within $\pm 0.25\text{mm}$ of its true longitudinal position relative to Pins 1 and the highest pin number.
7. Applies to all 4 corners.
8. All leads or terminals.
9. 18 spaces for flat and dual-in-line packages.
16 spaces for chip carrier packages.
10. Lead centre when α is 0° .
11. Index corner only - 2 dimensions.
12. 3 non-index corners - 6 dimensions.
13. 4 Places.
14. 16 Places.

**FIGURE 3(a) - PIN ASSIGNMENT****FIGURE 3(b) - TRUTH TABLE (EACH TRANSCEIVER)**

CONTROL INPUTS		OUTPUT
\overline{G}	DIR	DATA
L	L	B data to A bus
L	H	A data to B bus
H	X	Z

NOTES

1. Logic Level Definitions: L = Low Level, H = High Level, Z = High Impedance, X = Irrelevant.

**FIGURE 3(c) - CIRCUIT SCHEMATIC****FIGURE 3(d) - FUNCTIONAL DIAGRAM**



2. **APPLICABLE DOCUMENTS**

The following documents form part of this specification and shall be read in conjunction with it:-

- (a) ESA/SCC Generic Specification No. 9000 for Integrated Circuits.
- (b) MIL-STD-883, Test Methods and Procedures for Micro-electronics.

3. **TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS**

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESA/SCC Basic Specification No. 21300 shall apply. In addition, the following abbreviations are used:-

- IOS/2 - One half of the true output short circuit current.
- IOZH - Off state, output current high.
- IOZL - Off state, output current low.
- ICCZ - Supply current, outputs disabled.

4. **REQUIREMENTS**

4.1 **GENERAL**

The complete requirements for procurement of the integrated circuits specified herein shall be as stated in this specification and ESA/SCC Generic Specification No. 9000 for Integrated Circuits. Deviations from the Generic Specification, applicable to this specification only, are listed in Para. 4.2.

Deviations from the applicable Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESA/SCC requirements and do not affect the components' reliability, are listed in the appendices attached to this specification.

4.2 **DEVIATIONS FROM GENERIC SPECIFICATION**

4.2.1 **Deviations from Special In-process Controls**

None.

4.2.2 **Deviations from Final Production Tests (Chart II)**



None.

4.2.3 **Deviations from Burn-in Tests (Chart III)**

- (a) Para. 7.1.1(a), "High Temperature Reverse Bias" tests and subsequent electrical measurements related to this test shall be omitted.
- (b) Para. 9.9.2, "Electrical Measurements at High and Low Temperatures": Only a test result summary, based on go-no-go tests and presented in histogram form is required.

4.2.4 **Deviations from Qualification Tests (Chart IV)**

None.

 	<p>ESA/SCC Detail Specification No. 9405/005</p>	<p>Rev. 'A'</p>	<p>PAGE 14 ISSUE 3</p>
---	--	-----------------	----------------------------

4.2.5 Deviations from Lot Acceptance Tests (Chart V)

None.

4.3 MECHANICAL REQUIREMENTS

4.3.1 Dimension Check

The dimensions of the integrated circuits specified herein shall be checked. They shall conform to those shown in Figure 2.

4.3.2 Weight

The maximum weight of the integrated circuits specified herein shall be 0.9 grammes for the flat package, 0.6 grammes for the chip carrier package and 3.2 grammes for the dual-in-line package.

4.4 MATERIALS AND FINISHES

The materials and finishes shall be as specified herein. Where a definite material is not specified, a material which will enable the integrated circuits specified herein to meet the performance requirements of this specification shall be used. Acceptance or approval of any constituent material does not guarantee acceptance of the finished product.

4.4.1 Case

The case shall be hermetically sealed and have a metal body with hard glass seals or a ceramic body and the lids shall be welded, brazed, preform-soldered or glass frit-sealed.

4.4.2 Lead Material and Finish

For dual-in-line and flat packages, the material shall be either Type 'D' or Type 'G' with either Type '4' or Type '7' finish in accordance with the requirements of ESA/SCC Basic Specification No. 23500. For chip carrier packages, the finish shall be either Type '4' or Type '7' in accordance with the requirements of ESA/SCC Basic Specification No. 23500. (See Table 1(a) for Type Variants).

4.5 MARKING

4.5.1 General

The marking of all components delivered to this specification shall be in accordance with the requirements of ESA/SCC Basic Specification No. 21700. Each component shall be marked in respect of:-

- (a) Lead Identification.
- (b) The SCC Component Number.
- (c) Traceability Information.

4.5.2 Lead Identification

For dual-in-line and flat packages, an index shall be located at the top of the package in the position defined in Note 1 to Figure 2 or, alternatively, a tab may be used to identify Pin No. 1. The pin numbering must be read with the index or tab on the left-hand side. For chip carrier packages, the index shall be as defined by Figure 2(b).



4.5.3 The SCC Component Number

Each component shall bear the SCC Component Number which shall be constituted and marked as follows:

940500503B

Detail Specification Number _____

Type Variant (see Table 1(a)) _____

Testing Level (B or C, as applicable) _____

4.5.4 Traceability Information

Each component shall be marked in respect of traceability information in accordance with the requirements of ESA/SCC Basic Specification No. 21700.

4.6 ELECTRICAL MEASUREMENTS

4.6.1 Electrical Measurements at Room Temperature

The parameters to be measured in respect of electrical characteristics are scheduled in Table 2. Unless otherwise specified, the measurements shall be performed at $T_{amb} = +22 \pm 3$ °C.

4.6.2 Electrical Measurements at High and Low Temperatures

The parameters to be measured at high and low temperatures are scheduled in Table 3. The measurements shall be performed at $T_{amb} = +125(+0-5)$ °C and $-55(+5-0)$ °C respectively.

4.6.3 Circuits for Electrical Measurements

Circuits for use in performing electrical measurements listed in Tables 2 and 3 of this specification are shown in Figure 4.

4.7 BURN-IN TESTS

4.7.1 Parameter Drift Values

The parameter drift values applicable to burn-in are specified in Table 4 of this specification. Unless otherwise stated, measurements shall be performed at $T_{amb} = +22 \pm 3$ °C. The parameter drift values (Δ) applicable to the parameters scheduled, shall not be exceeded. In addition to these drift value requirements, the appropriate limit value specified for a given parameter in Table 2 shall not be exceeded.

4.7.2 Conditions for Power Burn-in

The requirements for power burn-in are specified in Section 7 of ESA/SCC Generic Specification No. 9000. The conditions for power burn-in shall be as specified in Table 5 of this specification.

4.7.3 Electrical Circuits for Power Burn-in

Circuits for use in performing the power burn-in tests are shown in Figure 5 of this specification.



TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST)	LIMITS		UNIT
						MIN	MAX	
1	Functional Test	-	-	3(b)	Verify Truth Table with Load. Note 1	-	-	-
2 to 19	Input Current High Level 1	I_{IH1}	3010	4(a)	$V_{CC} = 5.5V$, $V_{IN} = 2.7V$ Note 2 (Pins 1-2-3-4-5-6-7-8-9-11-12-13-14-15-16-17-18-19)	-	-20	μA
20 to 21	Input Current High Level 2 (Max. Input Voltage)	I_{IH2}	3010	4(a)	$V_{CC} = 5.5V$, $V_{IN} = 7.0V$ (Pins 1-19)	-	100	μA
22 to 37	Input Current High Level 3 (Max. Input Voltage)	I_{IH3}	3010	4(a)	$V_{CC} = 5.5V$, $V_{IN} = 5.5V$ (Pins 2-3-4-5-6-7-8-9-11-12-13-14-15-16-17-18)	-	100	μA
38 to 55	Input Clamp Voltage	V_{IC}	3008	4(b)	$V_{CC} = 4.5V$, $I_{IN} = -18mA$ Note 3 (Pins 1-2-3-4-5-6-7-8-9-11-12-13-14-15-16-17-18-19)	-	-1.5	V
56 to 73	Input Current Low Level	I_{IL}	3009	4(c)	$V_{CC} = 5.5V$, $V_{IL} = 0.4V$ Note 2 (Pins 1-2-3-4-5-6-7-8-9-11-12-13-14-15-16-17-18-19)	-	-100	μA
74 to 89	Output Voltage Low Level	V_{OL}	3007	4(d)	$V_{CC} = 4.5V$, $V_{IH} = 2.0V$ $V_{IL} = 0.7V$, $I_{OL} = 12mA$ (Pins 2-3-4-5-6-7-8-9-11-12-13-14-15-16-17-18)	-	0.4	V
90 to 105	Output Voltage High Level 1	V_{OH1}	3006	4(e)	$V_{CC} = 4.5V$, $V_{IH} = 2.0V$ $V_{IL} = 0.7V$, $I_{OH} = -3.0mA$ (Pins 2-3-4-5-6-7-8-9-11-12-13-14-15-16-17-18)	2.4	-	V
106 to 121	Output Voltage High Level 2	V_{OH2}	3006	4(e)	$V_{CC} = 4.5V$, $V_{IH} = 2.0V$ $V_{IL} = 0.7V$, $I_{OH} = -12mA$ (Pins 2-3-4-5-6-7-8-9-11-12-13-14-15-16-17-18)	2.0	-	V

NOTES: See Page 19.



TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST)	LIMITS		UNIT
						MIN	MAX	
122 to 137	Output Voltage High Level 3	V_{OH3}	3006	4(e)	$V_{CC} = 4.5V$, $V_{IH} = 2.0V$ $V_{IL} = 0.7V$, $I_{OH} = -0.4mA$ (Pins 2-3-4-5-6-7-8-9-11- 12-13-14-15-16-17-18)	2.5	-	V
138 to 153	Output Voltage High Level 4	V_{OH4}	3006	4(e)	$V_{CC} = 5.5V$, $V_{IH} = 2.0V$ $V_{IL} = 0.7V$, $I_{OH} = -0.4mA$ (Pins 2-3-4-5-6-7-8-9-11- 12-13-14-15-16-17-18)	3.5	-	V
154 to 169	One Half of the True Output Short Circuit Current	$I_{OS/2}$	3011	4(f)	$V_{CC} = 5.5V$, $V_{OUT} = 2.25V$ Note 4 (Pins 2-3-4-5-6-7-8-9-11- 12-13-14-15-16-17-18)	-30	-112	mA
170 to 171	Supply Current Outputs High	I_{CCH}	3005	4(g)	$V_{CC} = 5.5V$ Note 5 (Pin 20)	-	48	mA
172 to 173	Supply Current Outputs Low	I_{CCL}	3005	4(g)	$V_{CC} = 5.5V$ Note 5 (Pin 20)	-	60	mA
174	Supply Current Outputs Disabled	I_{CCZ}	3005	4(g)	$V_{CC} = 5.5V$ Note 5 (Pin 20)	-	63	mA

NOTES: See Page 19.

TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST) (NOTE 6)	LIMITS		UNIT
						MIN	MAX	
175 to 190	Propagation Delay Low to High, from A to B	t _{PLH1}	3003	4(h)	V _{CC} = 4.5V and 5.5V C _L = 50pF, R ₁ = R ₂ = 500Ω <u>Pins</u> 2 to 18 6 to 14 3 to 17 7 to 13 4 to 16 8 to 12 5 to 15 9 to 11	3.0	15	ns
191 to 206	Propagation Delay Low to High, from B to A	t _{PLH2}	3003	4(h)	V _{CC} = 4.5V and 5.5V C _L = 50pF, R ₁ = R ₂ = 500Ω <u>Pins</u> 18 to 2 14 to 6 17 to 3 13 to 7 16 to 4 12 to 8 15 to 5 11 to 9	3.0	15	ns
207 to 222	Propagation Delay High to Low, from A to B	t _{PHL1}	3003	4(h)	V _{CC} = 4.5V and 5.5V C _L = 50pF, R ₁ = R ₂ = 500Ω <u>Pins</u> 2 to 18 6 to 14 3 to 17 7 to 13 4 to 16 8 to 12 5 to 15 9 to 11	3.0	13	ns
223 to 238	Propagation Delay High to Low, from B to A	t _{PHL2}	3003	4(h)	V _{CC} = 4.5V and 5.5V C _L = 50pF, R ₁ = R ₂ = 500Ω <u>Pins</u> 18 to 2 14 to 6 17 to 3 13 to 7 16 to 4 12 to 8 15 to 5 11 to 9	3.0	13	ns
239 to 270	Output Enable Time to High Level from \bar{G} to A or B	t _{PZH}	3003	4(h)	V _{CC} = 4.5V and 5.5V C _L = 50pF, R ₁ = R ₂ = 500Ω <u>Pins</u> 19 to 2 19 to 11 19 to 3 19 to 12 19 to 4 19 to 13 19 to 5 19 to 14 19 to 6 19 to 15 19 to 7 19 to 16 19 to 8 19 to 17 19 to 9 19 to 18	5.0	25	ns

NOTES: See Page 19.

**SCC**ESA/SCC Detail Specification
No. 9405/005

PAGE 19

ISSUE 3

TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST) (NOTE 6)	LIMITS		UNIT
						MIN	MAX	
271 to 302	Output Enable Time to Low Level from \overline{G} to A or B	t_{PZL}	3003	4(h)	$V_{CC} = 4.5V$ and $5.5V$ $C_L = 50pF$, $R_1 = R_2 = 500\Omega$ <u>Pins</u> 19 to 2 19 to 11 19 to 3 19 to 12 19 to 4 19 to 13 19 to 5 19 to 14 19 to 6 19 to 15 19 to 7 19 to 16 19 to 8 19 to 17 19 to 9 19 to 18	5.0	25	ns
303 to 334	Output Disable Time to High Level from \overline{G} to A or B	t_{PHZ}	3003	4(h)	$V_{CC} = 4.5V$ and $5.5V$ $C_L = 50pF$, $R_1 = R_2 = 500\Omega$ <u>Pins</u> 19 to 2 19 to 11 19 to 3 19 to 12 19 to 4 19 to 13 19 to 5 19 to 14 19 to 6 19 to 15 19 to 7 19 to 16 19 to 8 19 to 17 19 to 9 19 to 18	2.0	12	ns
335 to 366	Output Disable Time to Low Level from \overline{G} to A or B	t_{PLZ}	3003	4(h)	$V_{CC} = 4.5V$ and $5.5V$ $C_L = 50pF$, $R_1 = R_2 = 500\Omega$ <u>Pins</u> 19 to 2 19 to 11 19 to 3 19 to 12 19 to 4 19 to 13 19 to 5 19 to 14 19 to 6 19 to 15 19 to 7 19 to 16 19 to 8 19 to 17 19 to 9 19 to 18	4.0	18	ns

NOTES

- Go-no-go test with $V_{IL} = 0.3V$, $V_{IH} = 3.0V$, trip point 1.5V.
- For I/O Ports, the parameters include the Off-State Output Currents (I_{OZH} , I_{OZL}).
- All inputs and outputs not under test shall be open.
- No more than 1 output should be tested at a time.
- For I_{CCH} : For Data A Outputs: \overline{G} and DIR Grounded, all Data B at 4.5V.
: For Data B Outputs: \overline{G} Grounded, DIR and all Data A at 4.5V.
For I_{CCL} : For Data A Outputs: \overline{G} , DIR and all Data B Grounded.
: For Data B Outputs: \overline{G} and all Data A Grounded, DIR at 4.5V
For I_{CCZ} : \overline{G} at 4.5V
- Propagation delay measurements shall be performed as a go-no-go test on a 100% basis. Read-and-record measurements shall be performed on an LTPD7 sample basis following the Chart III Burn-in Test.



**TABLE 3 - ELECTRICAL MEASUREMENTS AT HIGH AND LOW TEMPERATURES,
+ 125(+ 0 – 5) °C AND – 55(+ 5 – 0) °C**

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST)	LIMITS		UNIT
						MIN	MAX	
1	Functional Test	-	-	3(b)	Verify Truth Table with Load. Note 1	-	-	-
2 to 19	Input Current High Level 1	I _{IH1}	3010	4(a)	V _{CC} = 5.5V, V _{IN} = 2.7V Note 2 (Pins 1-2-3-4-5-6-7-8-9-11-12-13-14-15-16-17-18-19)	-	-20	μA
20 to 21	Input Current High Level 2 (Max. Input Voltage)	I _{IH2}	3010	4(a)	V _{CC} = 5.5V, V _{IN} = 7.0V (Pins 1-19)	-	100	μA
22 to 37	Input Current High Level 3 (Max. Input Voltage)	I _{IH3}	3010	4(a)	V _{CC} = 5.5V, V _{IN} = 5.5V (Pins 2-3-4-5-6-7-8-9-11-12-13-14-15-16-17-18)	-	100	μA
38 to 55	Input Clamp Voltage	V _{IC}	3008	4(b)	V _{CC} = 4.5V, I _{IN} = -18mA Note 3 (Pins 1-2-3-4-5-6-7-8-9-11-12-13-14-15-16-17-18-19)	-	-1.5	V
56 to 73	Input Current Low Level	I _{IL}	3009	4(c)	V _{CC} = 5.5V, V _{IL} = 0.4V Note 2 (Pins 1-2-3-4-5-6-7-8-9-11-12-13-14-15-16-17-18-19)	-	-100	μA
74 to 89	Output Voltage Low Level	V _{OL}	3007	4(d)	V _{CC} = 4.5V, V _{IH} = 2.0V V _{IL} = 0.7V, I _{OL} = 12mA (Pins 2-3-4-5-6-7-8-9-11-12-13-14-15-16-17-18)	-	0.4	V
90 to 105	Output Voltage High Level 1	V _{OH1}	3006	4(e)	V _{CC} = 4.5V, V _{IH} = 2.0V V _{IL} = 0.7V, I _{OH} = -3.0mA (Pins 2-3-4-5-6-7-8-9-11-12-13-14-15-16-17-18)	2.4	-	V
106 to 121	Output Voltage High Level 2	V _{OH2}	3006	4(e)	V _{CC} = 4.5V, V _{IH} = 2.0V V _{IL} = 0.7V, I _{OH} = -12mA (Pins 2-3-4-5-6-7-8-9-11-12-13-14-15-16-17-18)	2.0	-	V

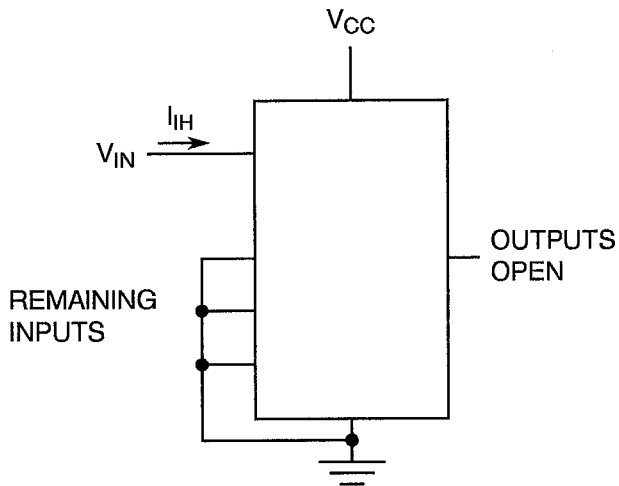
NOTES: See Page 19.



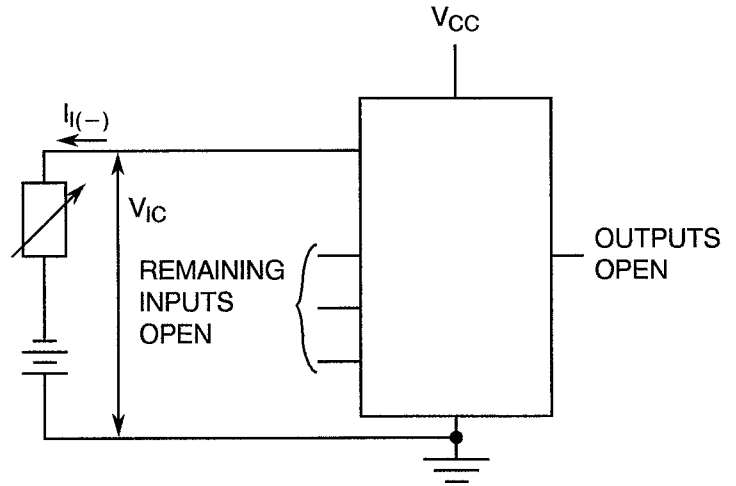
**TABLE 3 - ELECTRICAL MEASUREMENTS AT HIGH AND LOW TEMPERATURES,
+ 125(+ 0 – 5) AND – 55(+ 5 – 0) °C (CONT'D)**

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST)	LIMITS		UNIT
						MIN	MAX	
122 to 137	Output Voltage High Level 3	V _{OH3}	3006	4(e)	V _{CC} = 4.5V, V _{IH} = 2.0V V _{IL} = 0.7V, I _{OH} = – 0.4mA (Pins 2-3-4-5-6-7-8-9-11- 12-13-14-15-16-17-18)	2.5	-	V
138 to 153	Output Voltage High Level 4	V _{OH4}	3006	4(e)	V _{CC} = 5.5V, V _{IH} = 2.0V V _{IL} = 0.7V, I _{OH} = – 0.4mA (Pins 2-3-4-5-6-7-8-9-11- 12-13-14-15-16-17-18)	3.5	-	V
154 to 169	One Half of the True Output Short Circuit Current	I _{OS/2}	3011	4(f)	V _{CC} = 5.5V, V _{OUT} = 2.25V Note 4 (Pins 2-3-4-5-6-7-8-9-11- 12-13-14-15-16-17-18)	– 30	– 112	mA
170 to 171	Supply Current Outputs High	I _{CCH}	3005	4(g)	V _{CC} = 5.5V Note 5 (Pin 20)	-	48	mA
172 to 173	Supply Current Outputs Low	I _{CCL}	3005	4(g)	V _{CC} = 5.5V Note 5 (Pin 20)	-	60	mA
174	Supply Current Outputs Disabled	I _{CCZ}	3005	4(g)	V _{CC} = 5.5V Note 5 (Pin 20)	-	63	mA

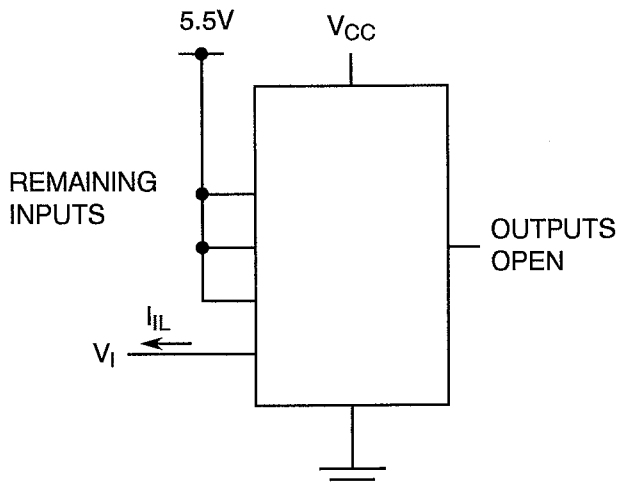
NOTES: See Page 19.

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS****FIGURE 4(a) - INPUT CURRENT HIGH LEVEL****NOTES**

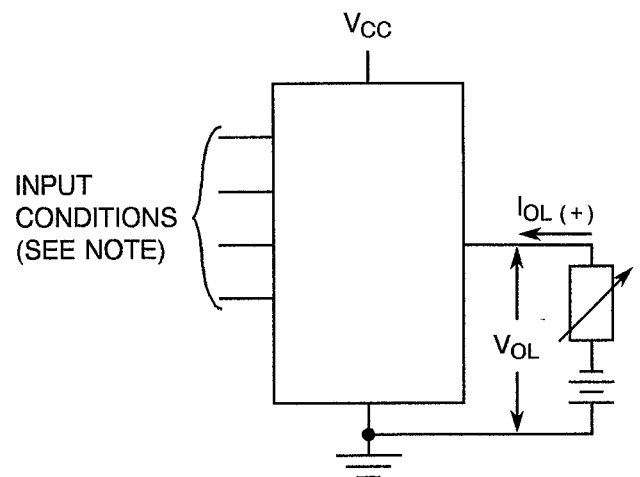
1. Each input to be tested separately.

FIGURE 4(b) - INPUT CLAMP VOLTAGE**NOTES**

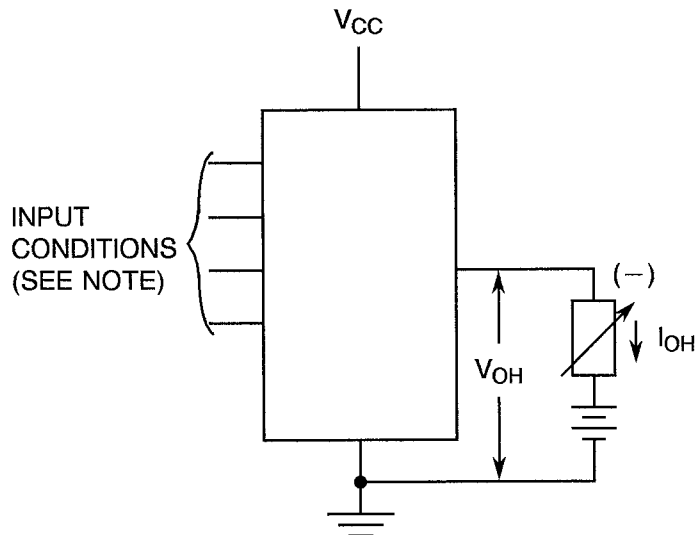
1. Each input to be tested separately.

FIGURE 4(c) - LOW LEVEL INPUT CURRENT**NOTES**

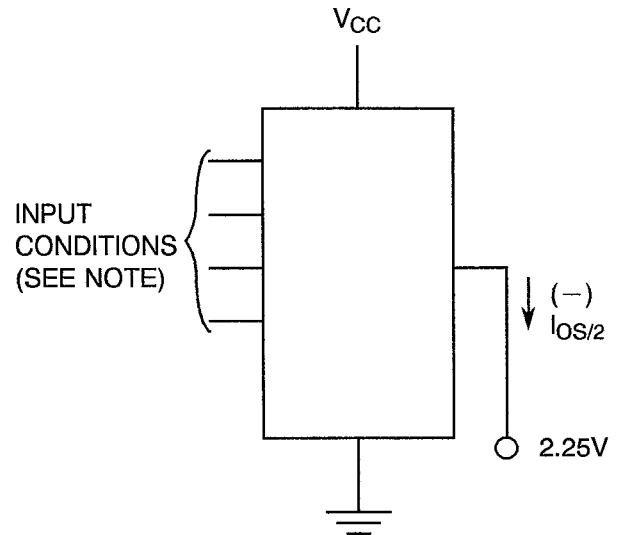
1. Each input to be tested separately.

FIGURE 4(d) - LOW LEVEL OUTPUT VOLTAGE**NOTES**

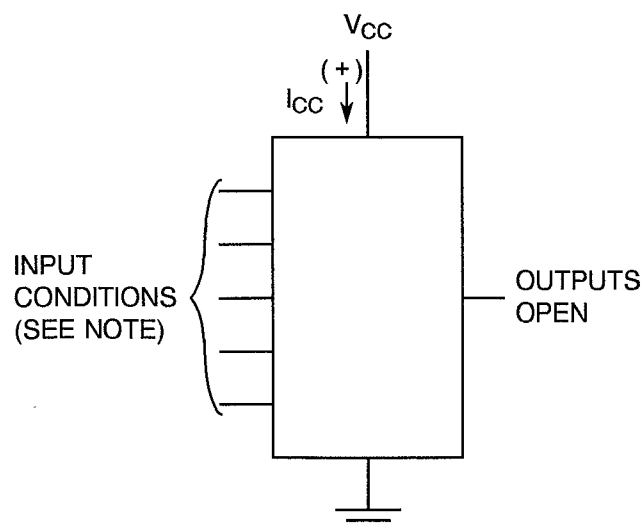
1. For Data A outputs: All Inputs at V_{IL} .
For Data B outputs: \overline{G} and Data A Inputs at V_{IL} , DIR at V_{IH} min.

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(e) - HIGH LEVEL OUTPUT VOLTAGE****NOTES**

- For Data A outputs: \overline{G} and DIR at V_{IL} .
Each Data B in turn at V_{IH} min., with all others at V_{IL} .
For Data B outputs: \overline{G} at V_{IL} , DIR at V_{IH} min.
Each Data A in turn at V_{IH} min., all others at V_{IL} .

FIGURE 4(f) - ONE HALF SHORT CIRCUIT OUTPUT CURRENT**NOTES**

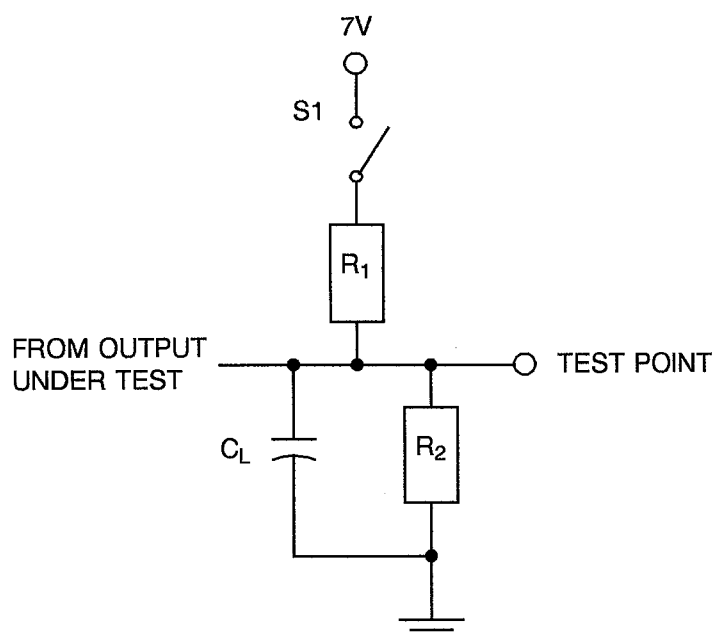
- For Data A outputs: \overline{G} and DIR Grounded.
Each Data B in turn at 4.5V with all others Grounded.
For Data B outputs: \overline{G} at V_{IL} , DIR at V_{IH} min.
Each Data A in turn at 4.5V with all others Grounded.

FIGURE 4(g) - SUPPLY CURRENT**NOTES**

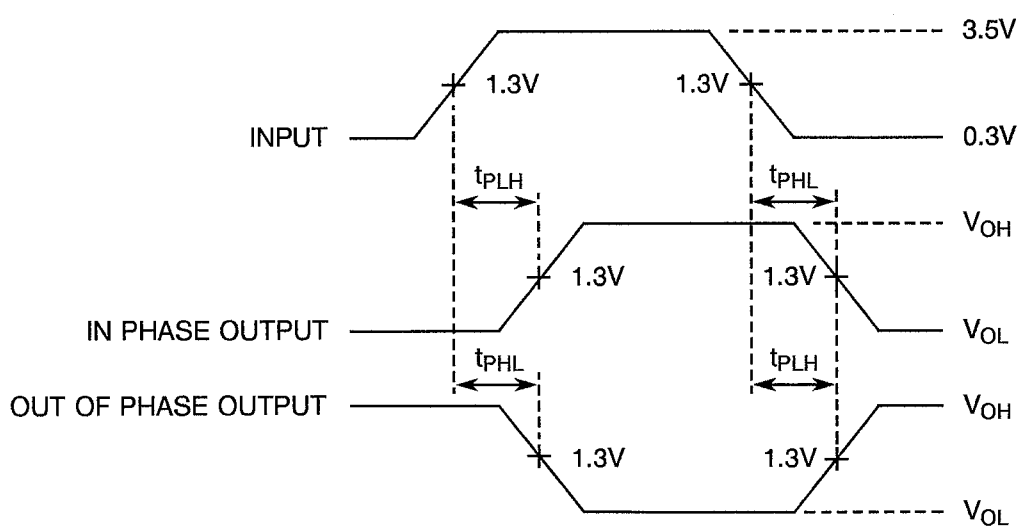
- See Note 5 on Page 19.

FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)

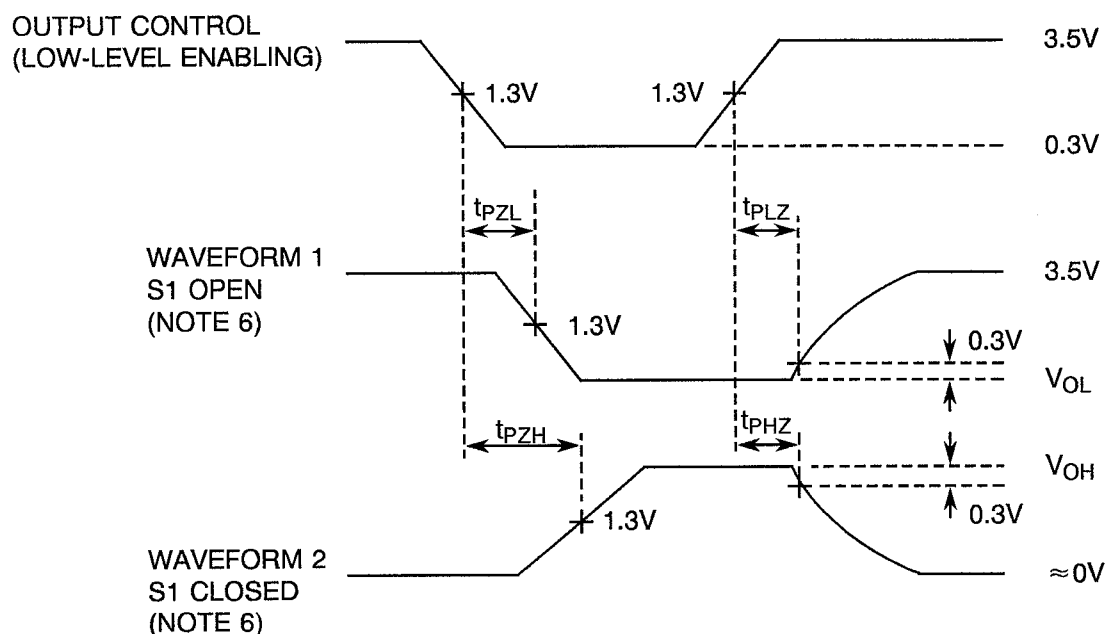
FIGURE 4(h) - DYNAMIC TEST AND SWITCHING WAVEFORMS



VOLTAGE WAVEFORMS - PROPAGATION DELAY TIMES



NOTES: See Note 5 on Page 25.

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(h) - DYNAMIC TEST AND SWITCHING WAVEFORMS (CONTINUED)****VOLTAGE WAVEFORMS - ENABLE AND DISABLE TIMES****NOTES**

1. The generator has the following characteristics: $t_r = t_f = 2\text{ns}$, $\text{PRR} = 1\text{MHz}$, $Z_{\text{out}} = 50\Omega$, Duty Cycle = 50%.
2. $C_L = 50\text{pF} \pm 5\%$ including scope probe, wiring and stray capacitance without package in test fixture.
3. Each transceiver tested separately.
4. $R_1 = R_2 = 500\Omega \pm 5\%$.
5. For measurement of Propagation Times, Switch S1 is open.
6. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the Output Control.

Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the Output Control.

**SCC**

ESA/SCC Detail Specification
No. 9405/005

PAGE 26

ISSUE 3

TABLE 4 - PARAMETER DRIFT VALUES

NO.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS (Δ)	UNIT
2 to 19	Input Current High Level 1	I_{IH1}	As per Table 2	As per Table 2	± 20 or (1) ± 0.5	% μA
56 to 73	Input Current Low Level	I_{IL}	As per Table 2	As per Table 2	± 10	μA
74 to 89	Output Voltage Low Level	V_{OL}	As per Table 2	As per Table 2	± 60	mV
90 to 105	Output Voltage High Level 1	V_{OH1}	As per Table 2	As per Table 2	± 200	mV
106 to 121	Output Voltage High Level 2	V_{OH2}	As per Table 2	As per Table 2	± 200	mV
122 to 137	Output Voltage High Level 3	V_{OH3}	As per Table 2	As per Table 2	± 200	mV
138 to 153	Output Voltage High Level 4	V_{OH4}	As per Table 2	As per Table 2	± 200	mV

NOTES

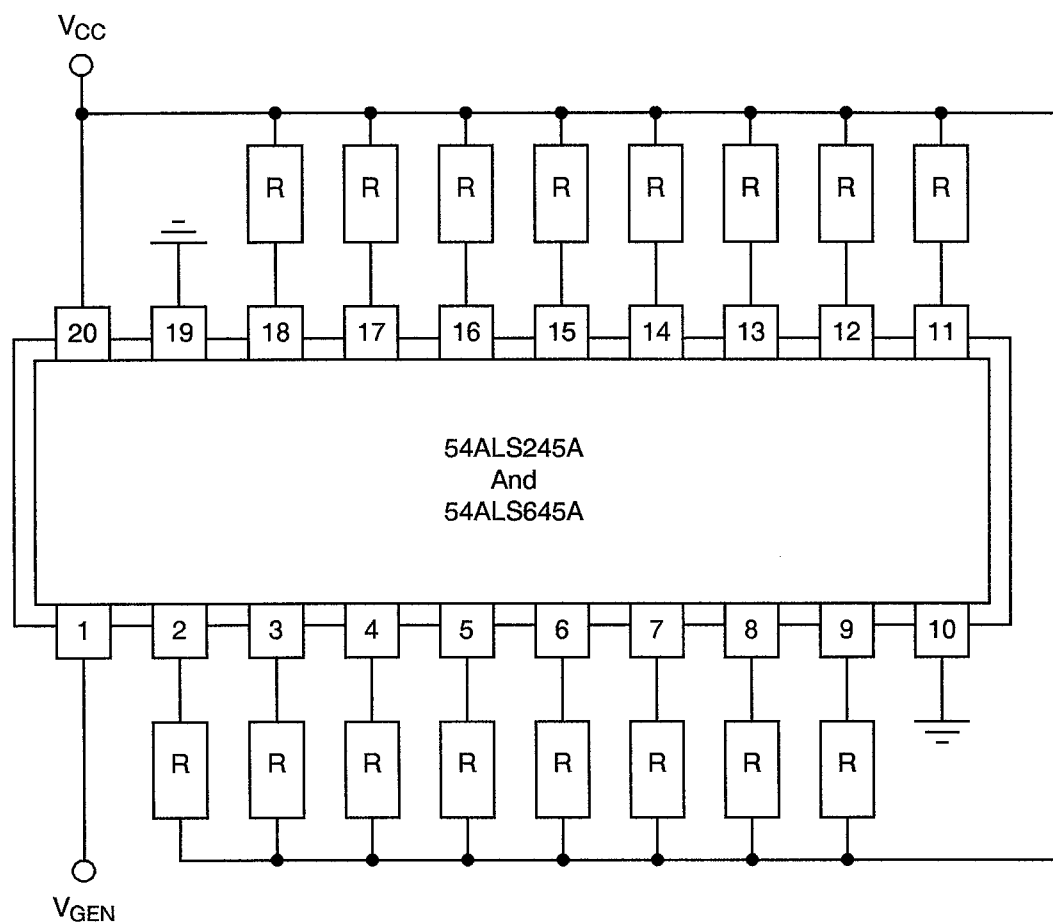
1. Whichever is greater referred to the initial value.

TABLE 5 - CONDITIONS FOR POWER BURN-IN AND OPERATING LIFE TEST



NO.	CHARACTERISTICS	SYMBOL	CONDITION	UNIT
1	Ambient Temperature	T_{amb}	+ 125(+ 0 – 5)	$^{\circ}C$
2	Power Supply Voltage	V_{CC}	+ 5(+ 0.5 – 0)	V
3	Pulse Voltage	V_{GEN}	0.5 max. to 3.0 min.	Vac
4	Frequency	f	100 (See Note 1)	Hz
5	Fan-out	-	10	-
6	Rise Time	t_r	50 max.	μs
7	Fall Time	t_f	50 max.	μs
8	Duty Cycle	-	20 min.	%

NOTES

1. Tolerance $\pm 10\%$.

**FIGURE 5 - ELECTRICAL CIRCUIT FOR POWER BURN-IN AND OPERATING LIFE TEST****NOTES**

1. $R = 380\Omega$.

 	<p>ESA/SCC Detail Specification No. 9405/005</p>		<p>PAGE 28 ISSUE 3</p>
--	--	--	----------------------------

4.8 ENVIRONMENTAL AND ENDURANCE TESTS (CHARTS IV AND V OF ESA/SCC GENERIC SPECIFICATION NO. 9000)

4.8.1 Electrical Measurements on Completion of Environmental Tests

The parameters to be measured on completion of environmental tests are scheduled in Table 6. Unless otherwise stated, the measurements shall be performed at $T_{amb} = +22 \pm 3$ °C.

4.8.2 Electrical Measurements at Intermediate Points during Endurance Tests

The parameters to be measured at intermediate points during endurance tests are as scheduled in Table 6 of this specification. Unless otherwise stated, the measurements shall be performed at $T_{amb} = +22 \pm 3$ °C.

4.8.3 Electrical Measurements on Completion of Endurance Tests

The parameters to be measured on completion of endurance testing are as scheduled in Table 6 of this specification. Unless otherwise stated, the measurements shall be performed at $T_{amb} = +22 \pm 3$ °C.

4.8.4 Conditions for Operating Life Tests

The requirements for operating life testing are specified in Section 9 of ESA/SCC Generic Specification No. 9000. The conditions for operating life testing shall be as specified in Table 5 of this specification.

4.8.5 Electrical Circuits for Operating Life Tests

Circuits for use in performing the operating life tests are shown in Figure 5.

4.8.6 Conditions for High Temperature Storage Test

The requirements for the high temperature storage test are specified in ESA/SCC Generic Specification No. 9000. The conditions for high temperature storage shall be $T_{amb} = +150(+0-5)$ °C.



TABLE 6 - ELECTRICAL MEASUREMENTS ON COMPLETION OF ENVIRONMENTAL TESTS AND AT INTERMEDIATE POINTS AND ON COMPLETION OF ENDURANCE TESTS

NO.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS		UNIT
					(Δ)	ABSOLUTE	
2 to 19	Input Current High Level 1	I _{IH1}	As per Table 2	As per Table 2	± 1	-	μA
20 to 21	Input Current High Level 2 (Max. Input Voltage)	I _{IH2}	As per Table 2	As per Table 2	-	100	μA
22 to 37	Input Current High Level 3 (Max. Input Voltage)	I _{IH3}	As per Table 2	As per Table 2	-	100	μA
56 to 73	Input Current Low Level	I _{IL}	As per Table 2	As per Table 2	± 10	-	μA
74 to 89	Output Voltage Low Level	V _{OL}	As per Table 2	As per Table 2	± 60	-	mV
90 to 105	Output Voltage High Level 1	V _{OH1}	As per Table 2	As per Table 2	± 200	-	mV
106 to 121	Output Voltage High Level 2	V _{OH2}	As per Table 2	As per Table 2	± 200	-	mV
122 to 137	Output Voltage High Level 3	V _{OH3}	As per Table 2	As per Table 2	± 200	-	mV
138 to 153	Output Voltage High Level 4	V _{OH4}	As per Table 2	As per Table 2	± 200	-	mV
170 to 171	Supply Current Outputs High	I _{CCH}	As per Table 2	As per Table 2	± 20	-	%
172 to 173	Supply Current Outputs Low	I _{CCL}	As per Table 2	As per Table 2	± 20	-	%
174	Supply Current Outputs Disabled	I _{CCZ}	As per Table 2	As per Table 2	± 20	-	%

**SCC**

ESA/SCC Detail Specification
No. 9405/005

PAGE 30

ISSUE 3

APPENDIX 'A'Page 1 of 1**AGREED DEVIATIONS FOR TEXAS INSTRUMENTS (F)**

ITEMS AFFECTED	DESCRIPTION OF DEVIATIONS
Para. 4.2.1	Scanning Electron Microscope (SEM) Inspection may be performed using TIF document TIF 3.61.610.001.
Para. 4.2.2	Prior to Die Shear Test TIF may perform a Radiographic Inspection on the randomly chosen samples to be subjected to this test, using TIF document TI 50.42-3002.
Para. 4.2.3	Radiographic Inspection may be performed using TIF document TI 50.42-3002.